

# 1A, 50V - 1000V High Efficient Surface Mount Rectifier

### **FEATURES**

- Glass passivated chip junction
- Ideal for automated placement
- Low forward voltage drop
- Ultrafast recovery time for high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- DC to DC converter
- Switching mode converters and inverters
- Lighting application
- Snubber
- Freewheeling application

## **MECHANICAL DATA**

- Case: DO-214AC (SMA)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.060g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
I <sub>F</sub>	1	А	
V <sub>RRM</sub>	50 - 1000	V	
I <sub>FSM</sub>	30	А	
T <sub>J MAX</sub>	150	°C	
Package	DO-214AC (SMA)		
Configuration	Single die		





DO-214AC (SMA)



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)									
PARAMETER	SYMBOL	US1A	US1B	US1D	US1G	US1J	US1K	US1M	UNIT
Marking code on the device		US1A	US1B	US1D	US1G	US1J	US1K	US1M	
Repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	35	70	140	280	420	560	700	V
Forward current	I <sub>F</sub>				1				А
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>				30				A
Junction temperature	TJ			- :	55 to +1	50			°C
Storage temperature	T <sub>STG</sub>			- :	55 to +1	50			°C



THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-lead thermal resistance	R <sub>θJL</sub>	27	°C/W	
Junction-to-ambient thermal resistance	R <sub>eja</sub>	75	°C/W	

PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage <sup>(1)</sup>	US1A US1B US1D US1G	I <sub>F</sub> = 1A, T <sub>J</sub> = 25°C	V <sub>F</sub>	-	1.0	V
J. J	US1J US1K US1M			-	1.7	V
Reverse current @ rated V <sub>R</sub> <sup>(2)</sup>		$T_J = 25^{\circ}C$		-	5	μA
		T <sub>J</sub> = 125°C	- I <sub>R</sub>	-	150	μA
Junction capacitance	US1A US1B US1D US1G	1MHz, V <sub>R</sub> = 4.0V	CJ	15	-	pF
	US1J US1K US1M			10	-	pF
US1A US1B US1D US1G US1J US1J US1K US1M	$I_F = 0.5A, I_R = 1.0A,$	t <sub>rr</sub>	-	50	ns	
	US1K	I <sub>rr</sub> = 0.25A		-	75	ns

#### Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING	
US1x	DO-214AC (SMA)	7,500 / Tape & Reel	

Notes:

1. "x" defines voltage from 50V(US1A) to 1000V(US1M)



## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

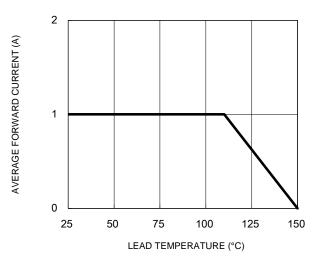
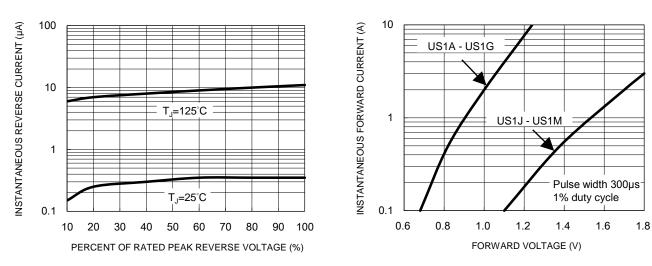


Fig.1 Forward Current Derating Curve

#### **Fig.3 Typical Reverse Characteristics**



#### Fig.5 Maximum Non-Repetitive Forward Surge Current

100

10

1

0.1

CAPACITANCE (pF)

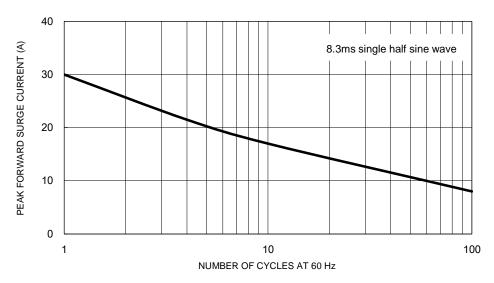


Fig.2 Typical Junction Capacitance

US1J - US1M

1

f=1.0MHz Vsig=50mVp-p US1A - US1G

10

REVERSE VOLTAGE (V)

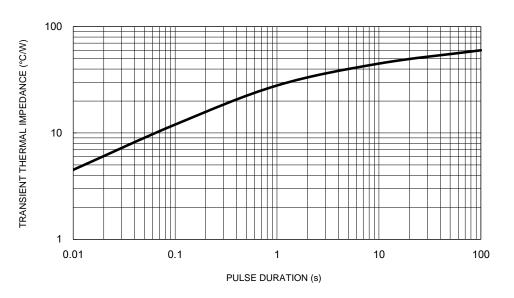
**Fig.4 Typical Forward Characteristics** 

100



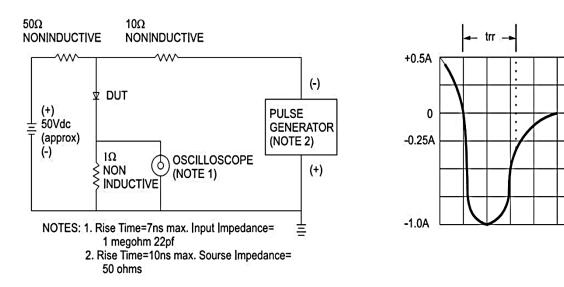
## **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 



#### Fig.6 Typical Transient Thermal Characteristics

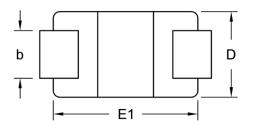
Fig.7 Reverse Recovery Time Characteristic And Test Circuit Diagram

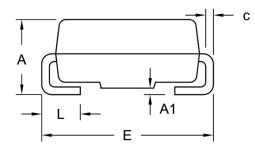




## **PACKAGE OUTLINE DIMENSIONS**

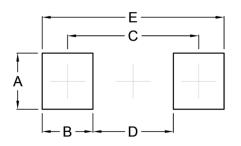
DO-214AC (SMA)





DIM.	Unit (mm)		Unit	inch)	
	Min.	Max.	Min.	Max.	
А	1.99	2.50	0.078	0.098	
A1	0.10	0.20	0.004	0.008	
b	1.27	1.58	0.050	0.062	
с	0.15	0.31	0.006	0.012	
D	2.29	2.83	0.090	0.111	
E	4.95	5.33	0.195	0.210	
E1	4.06	4.60	0.160	0.181	
L	0.90	1.41	0.035	0.056	

## SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	1.68	0.066
В	1.52	0.060
С	3.93	0.155
D	2.41	0.095
E	5.45	0.215

## **MARKING DIAGRAM**



P/N	= Marking Code
G	= Green Compound
YW	= Date Code

= Factory Code F



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